



SOT-23 Formed SMD Package

CMBT5401

SILICON P-N-P HIGH-VOLTAGE TRANSISTOR

P-N-P transistor

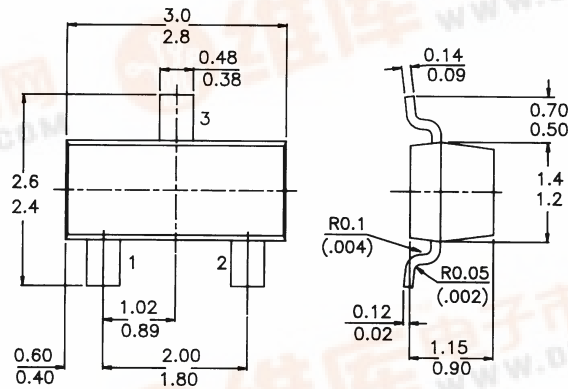
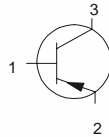
Marking

CMBT5401 = 2L

PACKAGE OUTLINE DETAILS
ALL DIMENSIONS IN mm

Pin configuration

- 1 = BASE
- 2 = EMITTER
- 3 = COLLECTOR



ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)

$-V_{CBO}$ max. 160 V

Collector-emitter voltage (open base)

$-V_{CEO}$ max. 150 V

Collector current

$-I_C$ max. 500 mA

Total power dissipation up to $T_{amb} = 25^\circ\text{C}$

P_{tot} max. 250 mW

Collector-emitter saturation voltage

$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}$

V_{CEsat} max. 0.5 V

D.C. current gain

$I_C = 10 \text{ mA}; V_{CE} = -5 \text{ V}$

h_{FE} 60 to 240

RATINGS (at $T_A = 25^\circ\text{C}$ unless otherwise specified)

Limiting values

Collector-base voltage (open emitter)

$-V_{CBO}$ max. 160 V

Collector-emitter voltage (open base)

$-V_{CEO}$ max. 150 V

Emitter-base voltage (open collector)

$-V_{EBO}$ max. 5 V

Collector current

$-I_C$ max. 500 mA



CMBT5401

Total power dissipation up to $T_{amb} = 25^{\circ}\text{C}$	P_{tot}	max	250 mW
Junction temperature	T_j	max.	150 $^{\circ}\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^{\circ}\text{C}$

THERMAL RESISTANCE

from junction to ambient	$R_{th\ j-a}$	500 K/W
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CHARACTERISTICS (at $T_A = 25^{\circ}\text{C}$ unless otherwise specified)

Collector cut-off current

$I_E = 0$; $-V_{CB} = 120\text{ V}$	$-I_{CBO}$	max.	50 nA
$I_E = 0$; $-V_{CB} = 120\text{ V}$; $T_{amb} = 150^{\circ}\text{C}$	$-I_{CBO}$	max.	50 μA

Breakdown voltages

$I_C = 1\text{ mA}$; $I_B = 0$	$-V_{(BR)CEO}$	min.	150 V
$I_C = 100\text{ }\mu\text{A}$; $I_E = 0$	$-V_{(BR)CBO}$	min.	160 V
$I_C = 0$; $I_E = 10\text{ }\mu\text{A}$	$-V_{(BR)EBO}$	min.	5 V

Saturation voltages

$-I_C = 10\text{ mA}$; $-I_B = 1\text{ mA}$	$-V_{CEsat}$	max.	0.2 V
	$-V_{BEsat}$	max.	1 V
$-I_C = 50\text{ mA}$; $-I_B = 5\text{ mA}$	$-V_{CEsat}$	max.	0.5 V
	$-V_{BEsat}$	max.	1 V

D.C. current gain

$I_C = 1\text{ mA}$; $-V_{CE} = 5\text{ V}$	h_{FE}	min.	50
$I_C = 10\text{ mA}$; $-V_{CE} = 5\text{ V}$	h_{FE}	min.	60
		max.	240
$I_C = 50\text{ mA}$; $-V_{CE} = 5\text{ V}$	h_{FE}	min.	50

Small-signal current gain

$I_C = 1\text{ mA}$; $-V_{CE} = 10\text{ V}$; $f = 1\text{ kHz}$	h_{fe}	min.	40
		max.	200

Output capacitance at $f = 1\text{ MHz}$

$I_E = 0$; $-V_{CB} = 10\text{ V}$	C_o	max.	6 pF
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Transition frequency at $f = 100\text{ MHz}$

$-I_C = 10\text{ mA}$; $-V_{CE} = 10\text{ V}$; $T_{amb} = 25^{\circ}\text{C}$	f_T	min.	100 MHz
		max.	300 MHz

Noise figure at $R_S = 10\text{ }\Omega$

$I_C = 200\text{ }\mu\text{A}$; $-V_{CE} = 5\text{ V}$			
$f = 10\text{ Hz to }15.7\text{ kHz}$; $T_{amb} = 25^{\circ}\text{C}$	F	max.	8 dB

Customer Notes

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